Amplifier Transistor

Symbol

 V_{CE}

V_{CB}

 V_{EB}

lc

 P_D

 P_D

T_J, T_{stg}

Symbol

 $R_{\theta JA}$

R_{0JC}

abilit Pher Pherson

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the

Recommended Operating Conditions may affect device reliability.

PNP Silicon

Features

• This is a Pb-Free Device*

Rating

MAXIMUM RATINGS

Collector - Emitter Voltage

Collector Current - Continuous

Operating and Storage Junction

Total Device Dissipation @ T_A = 25°C

Total Device Dissipation @ T_C = 25°C

THERMAL CHARACTERISTICS

Characteristic

Thermal Resistance, Junction-to-Ambient

Thermal Resistance, Junction-to-Case

Collector - Base Voltage

Emitter-Base Voltage

Derate above 25°C

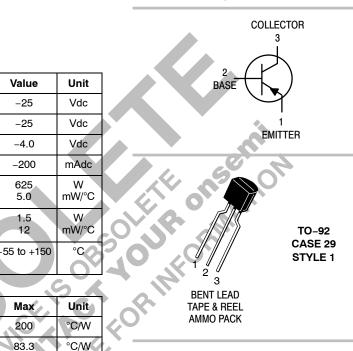
Derate above 25°C

Temperature Range

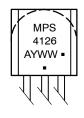


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MARKING DIAGRAM



= Assembly Location А Υ

= Year

= Work Week ww

= Pb-Free Package

(Note: Microdot may be in either location)

ORDERING INFORMATION

Device	Package	Shipping [†]
MPS4126RLRAG	TO–92 (Pb–Free)	2,000/Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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MPS4126

ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

Characteristic	Symbol	Min	Мах	Unit
OFF CHARACTERISTICS				
Collector – Emitter Breakdown Voltage $(I_C = -1.0 \text{ mA}, I_B = 0)$	V _{(BR)CEO}	-25	_	Vdc
Collector – Base Breakdown Voltage $(I_C = -10 \ \mu A, I_E = 0)$	V _{(BR)CBO}	-25	_	Vdc
Emitter – Base Breakdown Voltage $(I_C = 0, I_E = -10 \ \mu A)$	V _{(BR)EBO}	-4.0	_	Vdc
Collector Cutoff Current $(V_{CB} = -20 \text{ V}, I_E = 0)$	I _{CBO}	_	-50	nAdc
Emitter Cutoff Current ($V_{EB} = -3.0 \text{ V}, I_C = 0$)	I _{EBO}	-	-50	nAdc
ON CHARACTERISTICS				

ON CHARACTERISTICS

DC Current Gain (I _C = -2.0 mA, V _{CE} = -1.0 V) (I _C = -50 mA, V _{CE} = -1.0 V)		h _{FE}	120 60	360 -	-
Collector – Emitter Saturation Voltage (I _C = –50 mA, I _B = –5.0 mA)		V _{CE(sat)}		-0.4	Vdc
Base – Emitter Saturation Voltage ($I_C = -50$ mA, $I_B = -5.0$ mA)		V _{BE(sat)}	- 0	-0.95	Vdc
SMALL-SIGNAL CHARACTERISTICS					

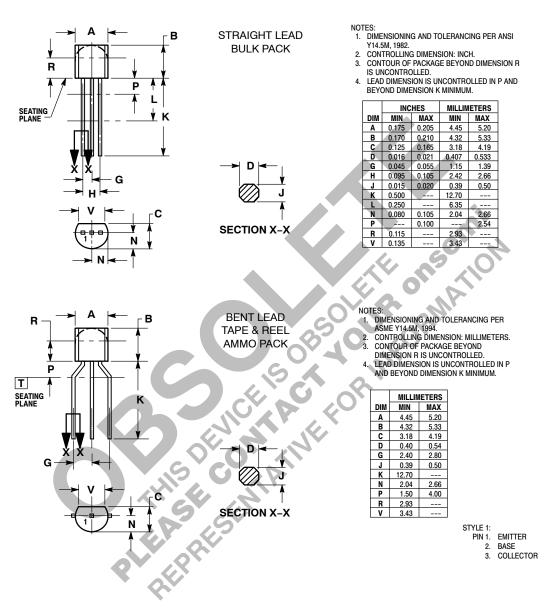
Current – Gain — Bandwidth Product (I _C = –10 mA, V _{CE} = –20 V, f = 100 MHz)	ίτ	170	-	MHz
Output Capacitance ($V_{CB} = -5.0 \text{ V}, I_E = 0, f = 1.0 \text{ MHz}$)	Cob	_	4.5	pF
Input Capacitance ($V_{EB} = -0.5 \text{ V}, I_C = 0, f = 1.0 \text{ MHz}$)	C _{ib}	_	11.5	pF
Small–Signal Current Gain ($I_C = -2.0 \text{ mA}, V_{CE} = 1.0 \text{ V}, f = 1.0 \text{ kHz}$)	h _{fe}	120	480	-
Noise Figure (I _C = -100 μ A, V _{CE} = -5.0 V, R _S = 1.0 kΩ, f = 1.0 kHz)	NF	-	4.0	dB

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MPS4126

PACKAGE DIMENSIONS

TO-92 (TO-226) CASE 29-11 ISSUE AM



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